## NSN 5962-01-262-2721

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View Online at https://aerobasegroup.com/nsn/5962-01-262-2721 **Body Length:** 0.350 inches **Body Width:** 0.350 inches **Maximum Power Dissipation Rating:** 0.6 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and bipolar and programmable **Inclosure Material:** Metal or plastic or ceramic **Inclosure Configuration:** Leaded chip carrier **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** C-2 mil-m-38510 **Current Rating Per Characteristic:** 12.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:** Pal **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 flat leads Shelf Life: N/a

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**Unit Of Measure:** 

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Demilitarization:

No

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